FAIRCHILD

SEMICONDUCTOR®

FIN1049 LVDS Dual Line Driver with Dual Line Receiver

General Description

This dual Driver-Receiver is designed for high speed interconnects utilizing Low Voltage Differential Signaling (LVDS) technology. The Driver accepts LVTTL inputs and translates them to LVDS outputs. The Receiver accepts LVDS inputs and translates them to LVTTL outputs. The LVDS levels have a typical differential output swing of 350mV which provide for low EMI at ultra low power dissipation even at high frequencies. The FIN1049 can accept LVPECL inputs for translating from LVPECL to LVDS. The En and Enb inputs are ANDed together to enable/disable the outputs. The enables are common to all four outputs. A single line driver and single line receiver function is also available in the FIN1019.

Features

- Greater than 400 Mbps data rate
- 3.3V power supply operation
- Low power dissipation
- Fail safe protection for open-circuit conditions

March 2003

Revised March 2003

- Meets or exceeds the TIA/EIA-644-A LVDS standard
- 16-pin TSSOP package saves space
- Flow-through pinout simplifies PCB layout
- Enable/Disable for all outputs
- Industrial operating temperature range: −40°C to +85°C

Ordering Code:

Order Number	Package Number	Package Description	č
FIN1049MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide	
Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.			

Pin Descriptions

Connection Diagram

Pin Name	Description
R _{IN1+} , R _{IN2+}	Non-Inverting LVDS Inputs
R _{IN1-} , R _{IN2-}	Inverting LVDS Inputs
D _{OUT1+} , D _{OUT2+}	Non-Inverting Driver Outputs
D _{OUT1-} , D _{OUT2-}	Inverting Driver Outputs
EN, ENb	Driver Enable Pins for All Outputs
R _{OUT1} , R _{OUT2}	LVTTL Output Pins for R_{OUT1} and R_{OUT2}
D _{IN2} , D _{IN2}	LVTTL Input Pins for D_{IN1} and D_{IN2}
V _{CC}	Power Supply (3.3V)
GND	Ground

R _{IN1-}	- 1	\bigcirc	16	- EN
R _{IN1+}	2		15	- ROUT1
R _{IN2+} -	3		14	- R _{OUT2}
R _{IN2-}	4		13	- GND
DOUT2-	5		12	– v _{DD}
DOUT2+ -	6		11	DIN2
DOUT1+	7		10	DIN1
DOUT1-	- 8		9	- ENb

© 2003 Fairchild Semiconductor Corporation DS500846

FIN1049

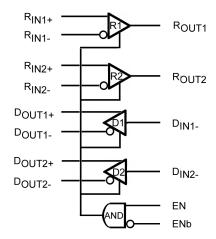
Function Table

Inputs		Outputs (LVTTL)		Inputs (LVDS) (Note 1)		Outputs (LVDS)	
EN	ENb	R _{OUT1}	R _{OUT2}	R _{IN#+}	R _{IN#-}	D _{OUT#+}	D _{OUT#}
Н	L	ON	ON			ON	ON
Н	Н	Z	Z			Z	Z
L	Н	Z	Z			Z	Z
L	L	Z	Z			Z	Z
Н	L	н	н		Current Condition		

L HIGH Logic Level L = LOW Logic Level or OPEN X = Don't Care Z = High Impedance

Note 1: Any unused Receiver Inputs should be left Open.

Functional Diagram



www.fairchildsemi.com

2

Absolute Maximum Ratings(Note 2)

Supply Voltage (V _{CC})	-0.5V to +4.6V
LVDS DC Input Voltage (VIN)	-0.5V to +4.6V
LVDS DC Output Voltage (V _{OUT})	-0.5V to +4.6V
Driver Short Circuit Current (I _{OSD})	Continuous 10mA
Storage Temperature Range (T _{STG})	$-65^{\circ}C$ to $+150^{\circ}C$
Max Junction Temperature (T _J)	150°C
Lead Temperature (T _L)	
(Soldering, 10 seconds)	260°C
ESD (Human Body Model)	>7000V
ESD (Machine Model)	>250V

Recommended Operating Conditions

Supply Voltage (V_{CC}) Magnitude of Differential Voltage ($|V_{ID}|$) Operating Temperature (T_A)

Note 2: The "Absolute Maximum Ratings": are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature and output/input loading variables. Fairchild does not recommend operation of circuits outside databook specification.

DC Electrical Characteristics

Over supply voltage and operating temperature ranges, unless otherwise specified

Symbol	Parameter	Test Conditions	Min	Typ (Note 3)	Max	Units
	LVDS Input DC S	pecifications (R _{IN1+} , R _{IN1-} , R _{IN2+} , R _{IN2-}) See F	igure 1 and	Table 1		
V _{TH}	Differential Input Threshold HIGH	$V_{CM} = 1.2V_{CM} = 0.05V_{CM} = 2.25V_{CM}$		0.0	35.0	mV
V _{TL}	Differential Input Threshold LOW	VCM = 1.2V, 0.05V, 2.35V	-100	0.0		mV
VIC	Common Mode Voltage Range	$V_{ID} = 100 \text{mV}, V_{CC} = 3.3 \text{V}$	V _{ID} /2		$V_{CC} - (V_{ID}/2)$	V
I _{IN}	Input Current	$V_{CC} = 0V \text{ or } 3.6V, V_{IN} = 0V \text{ or } 2.8V$			±20.0	mA
	CMOS/	LVTTL Input DC Specifications (EN, ENb, D	_{IN1} , D _{IN2})			
VIH	Input High Voltage (LVTTL)		2.0		V _{CC}	V
V _{IL}	Input Low Voltage (LVTTL)		GND		0.8	V
I _{IN}	Input Current					
	(EN, ENb, $D_{IN1},D_{IN2},R_{INx+},\text{and}\\R_{INx-})$	$V_{IN} = 0V \text{ or } V_{CC}$			±20.0	μΑ
VIK	Input Clamp Voltage	$V_{IK} = -18 \text{mA}$	-1.5	-0.7		V
	LVDS Out	put DC Specifications (D _{OUT1+} , D _{OUT1-} , D _{OUT}	₁₂₊ , D _{OUT2-})		1	
V _{OD}	Output Differential Voltage		250	350	450	mV
ΔV_{OD}	V _{OD} Magnitude Change from	$R_L = 100\Omega$,			05.0	
	Differential LOW-to-HIGH	Driver Enabled,			35.0	mV
V _{OS}	Offset Voltage	See Figure 2	1.125	1.25	1.375	V
ΔV_{OS}	Offset Magnitude Change from	-1			05.0	
	Differential LOW-to-HIGH				25.0	mV
I _{OS}	Oh and Oliverith Ordered Organization	D _{OUT+} = 0V & D _{OUT-} = 0V, Driver Enabled			-9.0	mA
I _{OSD}	Short Circuit Output Current	V _{OD} = 0V, Driver Enabled			-9.0	mA
I _{OFF}	Power-Off Input or Output Current	$V_{CC} = 0V, V_{OUT} = 0V \text{ or } V_{CC}$			±20.0	μA
I _{OZD}	Disabled Output Leakage Current	Driver Disabled, D _{OUT+} = 0V or V _{CC}				
		or $D_{OUT-} = 0V$ or V_{CC}			±10.0	μA
	СМО	S/LVTTL Output DC Specifications (R _{OUT1} , F	R _{OUT2})	1		
V _{OH}	Output High Voltage	$I_{OH} = -2mA, V_{ID} = 200mV$	2.7			V
V _{OL}	Output Low Voltage	$I_{OL} = 2mA, V_{ID} = 200mV$		1	0.250	V
loz	Disabled Output Leakage Current	Driver Disabled, $R_{OUTn} = 0V \text{ or } V_{CC}$			±10.0	μA
I _{CC}	Power Supply Current (Note 4)	Drivers Enabled, Any Valid Input Condition		1	25.0	mA
I _{CCZ}	Power Supply Current	Drivers Disabled		1	10.0	mA
CIND	Input Capacitance	LVDS Input		3.0		pF
C _{OUT}	Output Capacitance	LVDS Output		4.0		pF
CINT	Input Capacitance	LVTTL Input		3.5		pF

Note 3: All typical values are at $T_A = 25^{\circ}C$ and with $V_{CC} = 3.3V$.

Note 4: Both driver and receiver inputs are static. All LVDS outputs have 100Ω load. None of the outputs have any lumped capacitive load.

FIN1049

3.0V to 3.6V

100mV to $V_{\mbox{\scriptsize CC}}$

-40°C to +85°C

FIN1049

AC Electrical Characteristics

Over supply voltage and operating temperature ranges, unless otherwise specified Min Max Typ Test Conditions Units Symbol Parameter (Note 5) Switching Characteristics - LVDS Outputs Differential Propagation Delay LOW-to-HIGH t_{PLHD} 2.0 ns Differential Propagation Delay HIGH-to-LOW 2.0 ns t_{PHLD} Differential Output Rise Time (20% to 80%) 0.2 1.0 ns t_{TLHD} Differential Output Fall Time (80% to 20%) 0.2 1.0 ns t_{THLD} See Figures 3, 4 Pulse Skew |t_{PLH} - t_{PHL}| 0.35 ns t_{SK(P)} t_{SK(LH)}, Channel-to-Channel Skew (Note 6) 0.35 ns t_{SK(HL)} Part-to-Part Skew (Note 7) 1.0 ns t_{SK(PP)} Differential Output Enable Time from Z-to-HIGH 6.0 ns t_{PZHD} Differential Output Enable Time from A-to-LOW 6.0 ns t_{PZLD} See Figures 5. 6 Differential Output Disable Time from HIGH-to-Z 3.0 ns t_{PHZD} Differential Output Disable Time from LOW-to-Z 3.0 t_{PLZD} ns See Figure 3 200 MHz Maximum Frequency (Note 8) f_{MAXD} Switching Characteristics - LVTTL Outputs Propagation Delay HIGH-to-LOW Measured from 20% to 80% signal 0.5 10 3.5 t_{PHL} ns Propagation Delay LOW-to-HIGH $V_{ID} = 200 mV;$ 0.5 1.0 3.5 ns t_{PLH} Pulse Skew Distributed Load 0.0 35.0 400 ps t_{SK1} Channel-to-Channel Skew $C_L = 15 pF$ and 50Ω ; 0.0 50.0 500 ps t_{SK2} Part-to-Part Skew $R_L = 1K\Omega;$ 0.0 1.0 ns t_{SK3} Transition Time I OW-to-HIGH V_{OS} = 1.2V; 01 0.25 14 ns t_{LHR} Transition Time HIGH-to-LOW See Figures 7, 8 0.1 0.18 1.4 ns t_{HLR} Disable Time HIGH-to-Z 2.2 4.5 8.0 ns t_{PHZ} Disable Time LOW-to-Z 1.3 3.5 8.0 t_{PI 7} ns See Figures 9, 10 Enable Time Z-to-HIGH t_{PZH} 18 3.0 70 ns Enable Time Z-to-LOW 0.9 7.0 1.4 t_{PZL} ns MHz Maximum Frequency (Note 9) See Figure 7 200 f_{MAXT}

Note 5: All typical values are at $T_A = 25^{\circ}C$ and with $V_{CC} = 3.3V$.

Note 6: $t_{SK(LH)}$, $t_{SK(HL)}$ is the skew between specified outputs of a single device when the outputs have identical loads and are switching in the same direction.

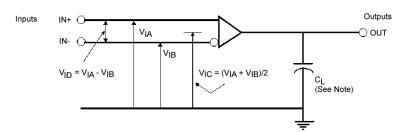
Note 7: $t_{SK(PP)}$ is the magnitude of the difference in propagation delay times between any specified terminals of two devices switching in the same direction (either LOW-to-HIGH or HIGH-to-LOW) when both devices operate with the same supply voltage, same temperature, and have identical test circuits. Note 8: f_{MAX} generator input conditions: $t_r = t_f < 1ns$ (10% to 90%), 50% duty cycle, 0V to 3V. Output criteria: duty cycle = 45% / 55%, $V_{OD} > 250$ mV, all chan-

Note 9: f_{MAXT} generator input conditions: $t_r = t_f < 1ns$ (10% to 90%), 50% duty cycle, $V_{ID} = 200mV$, $V_{CM} = 1.2V$. Output criteria: duty cycle = 45% / 55%, $V_{OH} > 2.7V$. $V_{OL} < 0.25V$, all channels switching.

Required Specifications

- 1. Human Body Model ESD and Machine Model ESD should be measured using MIL-STD-883C method 3015.7 standard.
- 2. Latch-up immunity should be tested to the EIA/JEDEC Standard Number 78 (EIA/JESD78).

FIN1049

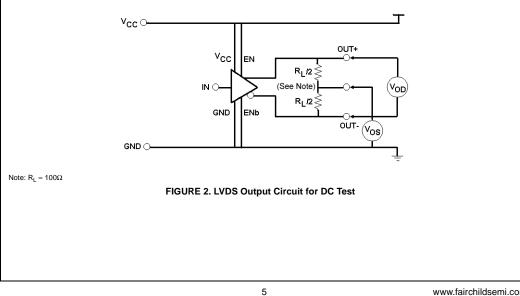


Note: $C_L = 15 pF$, includes all probe and jig capacitances

FIGURE 1. Differential Receiver Voltage Definitions Test Circuit

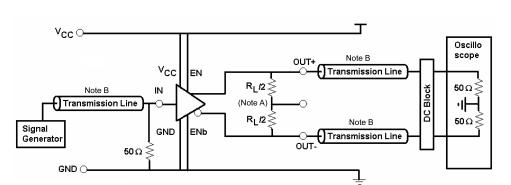
TABLE 1. Receiver Minimum and Maximum Input Threshold Test Voltages

Applied Voltages (V)		Resulting Differential Input Voltage (mV)	Resulting Common Mode Input Voltage (V)		
VIA	V _{IB}	V _{ID}	V _{IC}		
1.25	1.15	100	1.2		
1.15	1.25	-100	1.2		
V _{CC}	V _{CC} - 0.1	100	V _{CC} - 0.05		
V _{CC} - 0.1	V _{CC}	-100	V _{CC} - 0.05		
0.1	0.0	100	0.05		
0.0	0.1	-100	0.05		
1.75	0.65	1100	1.2		
0.65	1.75	-1100	1.2		
V _{CC}	V _{CC} - 1.1	1100	V _{CC} - 0.55		
V _{CC} - 1.1	V _{CC}	-1100	V _{CC} - 0.55		
1.1	0.0	1100	0.55		
0.0	1.1	-1100	0.55		



FIN1049

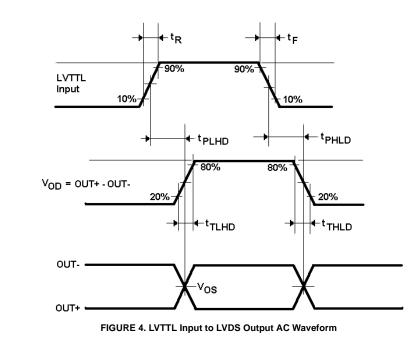
Required Specifications (Continued)

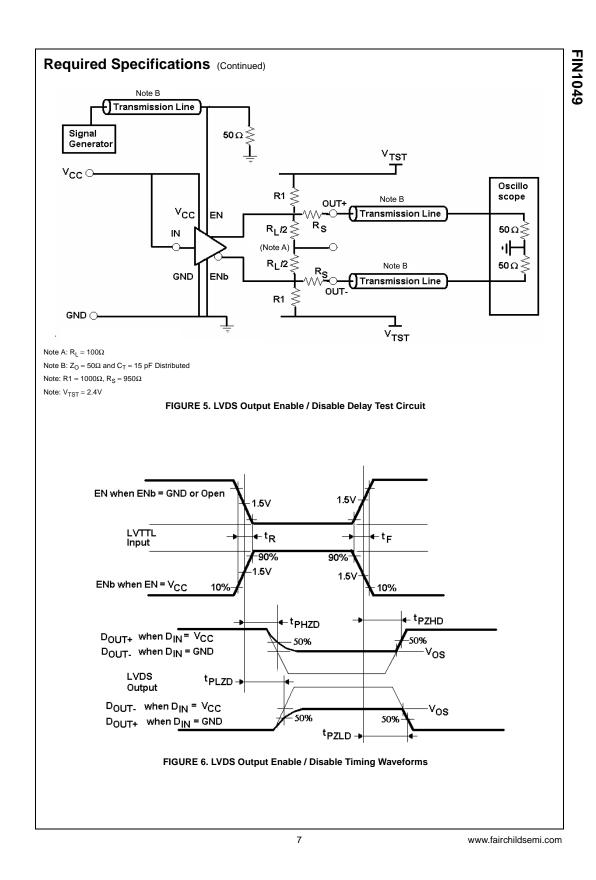


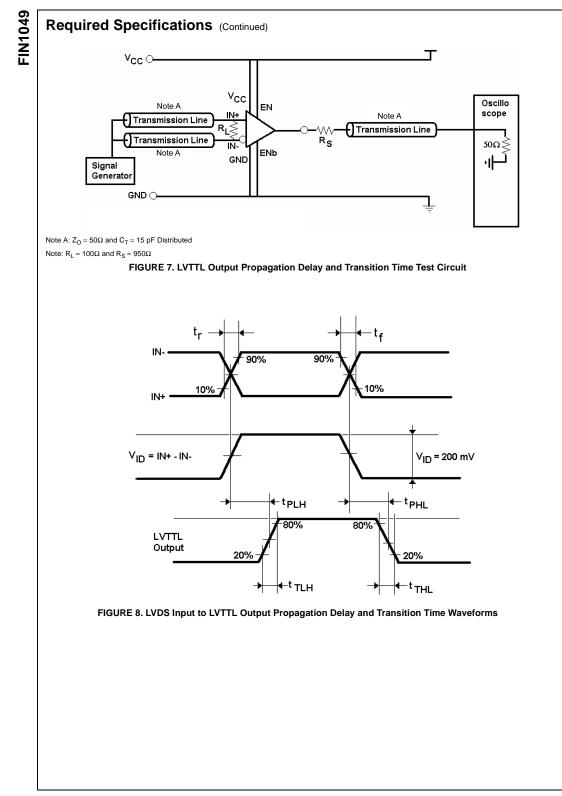
Note A: $R_L = 100\Omega$

Note B: $Z_0 = 50\Omega$ and $C_T = 15 \text{ pF}$ Distributed



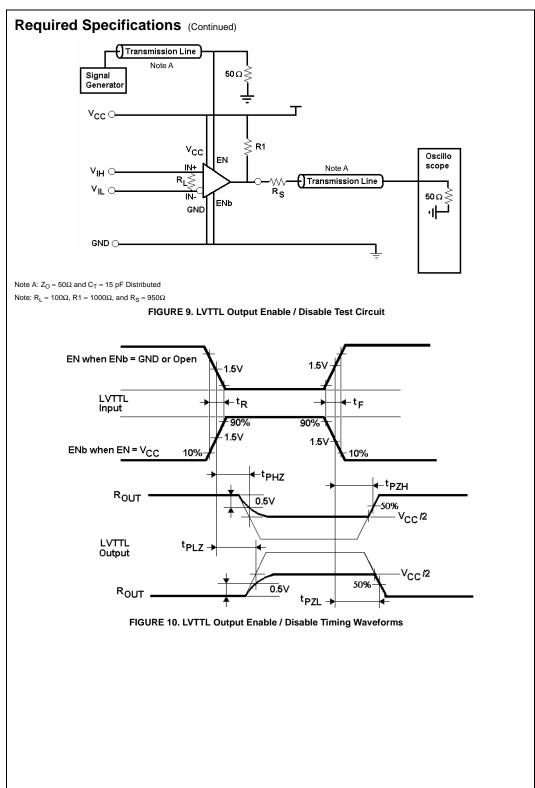






www.fairchildsemi.com

8



9

